SHARP PC4SD21NTZ Series

PC4SD21NTZ Series

■ Features

- 1. High repetitive peak OFF-state voltage (VDRM):800V
- 2. Low zero-cross voltage (VOXIMAX.]=20V)
- 3. Isolation voltage between input and output (V_{iso (rms)}:5kV)
- 4. Recognized by UL, file No. E64380 (model No.4SD21)
- 5. Approved by CSA, file No. CA95323 (model No.4SD21)
- 6. Approved by VDE(VDE0884), file No.127413 (available as an option)

■ Applications

- 1. Home appliances
- 2. OA equipment, FA equipment
- 3. SSRs

■ Model Line-up

Minimum trigger current (I _{FT[MAX.]})	Model No.		
5mA	PC4SD21NTZC *(PC4SD21YTZC)		
3mA	PC4SD21NTZD *(PC4SD21YTZD)		

*VDE(VDE0884) approved type

■ Absolute Maximum Ratings (T_a=25°C)

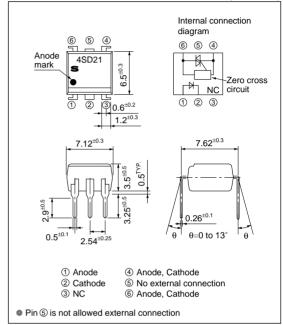
	Parameter	Symbol	Rating	Unit
Input	*1Forward current	I_F	50	mA
	Reverse voltage	V_R	6	V
Output	*1RMS ON-state current	I _{T (rms)}	0.1	A
	Peak one cycle surge current	I _{surge}	1.2 (50Hz sine wave)	A
	Repetitive peak OFF-state voltage	V_{DRM}	800	V
Operating temperature		T_{opr}	-30 to +100	°C
Storage temperature		T _{stg}	-55 to +125	°C
*2 Isolation voltage		V _{iso (rms)}	5	kV
Soldering temperature		T _{sol}	260 (For 10s)	°C

^{*1} The derating factors of absolute maximum ratings due to ambient temperature are shown in Fig.1, 2

V_{DRM}: 800V Phototriac Coupler for Triggering

■ Outline Dimensions





^{*2 40} to 60%RH, AC for 1minute, f=60Hz

50

μs

■ Electro	o-optical Chara	cteristics					($T_a=25^{\circ}C$
Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage		V_F	I _F =20mA	_	1.2	1.4	V
	Reverse current		I_R	V _R =3V	_	_	10-5	A
	Repetitive peak OFF-state current		I_{DRM}	$V_{\mathrm{D}} = V_{\mathrm{DRM}}$	-	-	3×10 ⁻⁶	A
	ON-state voltage		V_{T}	I _T =0.1mA	_	_	2.5	V
	Holding current		I_H	V _D =4V	0.1	_	3.5	mA
Output	Critical rate of rise of OFF-state voltage		dV/dt	$V_D=(1/\sqrt{2}) \cdot V_{DRM}$	500	1 000	_	V/µs
	Zero-cross voltage		V _{OX}	Resistance load, I _F =8mA	_	_	20	V
Transfer characteristics	Minimum trigger current PC4SD21NTZC PC4SD21NTZD		$V_{D}=4V, R_{I}=100\Omega$	_	-	5	mA	
		PC4SD21NTZD	I _{FT}	V _D =4V, K _L =10022	_	_	3	
	Isolation resistance		R _{ISO}	DC=500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω

 $V_D=4V, R_L=100\Omega, I_F=20mA$

Fig.1 RMS ON-state Current vs. Ambient Temperature

Turn-on time

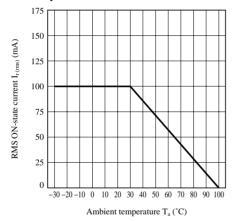


Fig.3 Forward Current vs. Forward Voltage

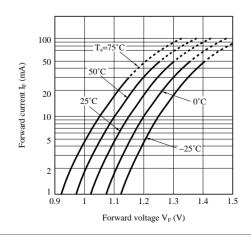


Fig.2 Forward Current vs. Ambient Temperature

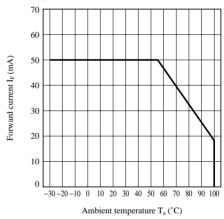


Fig.4 Minimum Trigger Current vs. Ambient Temperature

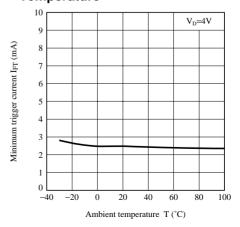


Fig.5 ON-state Voltage vs. Ambient Temperature

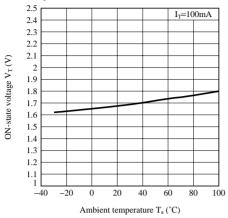


Fig.7 Repetitive Peak OFF-state Current vs. Ambient Temperature

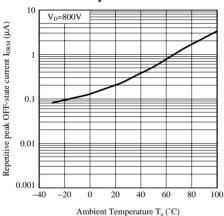


Fig.9 Turn-on Time vs. Forward Current

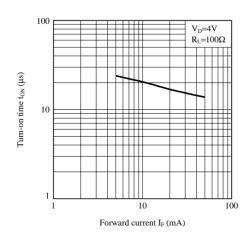


Fig.6 Holding Current vs. Ambient Temperature

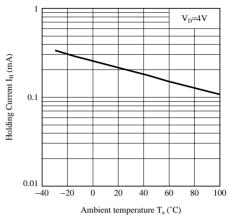


Fig.8 Relative Repetitive Peak OFF-state Voltage vs. Ambient Temperature

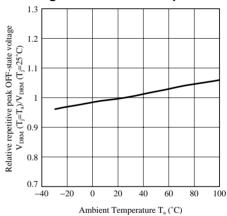
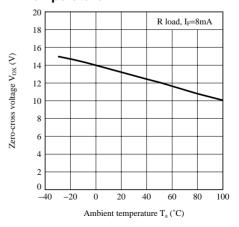


Fig.10 Zero-cross Voltage vs. Ambient Temperature



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